

Hari P Nair

List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/10984696/publications.pdf>

Version: 2024-02-01

21
papers

408
citations

687363

13
h-index

839539

18
g-index

21
all docs

21
docs citations

21
times ranked

692
citing authors

#	ARTICLE	IF	CITATIONS
1	Tilted spin current generated by the collinear antiferromagnet ruthenium dioxide. Nature Electronics, 2022, 5, 267-274.	26.0	64
2	Quantum oscillations and quasiparticle properties of thin film SrRuO_2 . Physical Review B, 2021, 104, .	3.2	15
3	Strain relaxation induced transverse resistivity anomalies in SrRuO_3 thin films. Physical Review B, 2020, 102, .	7.1	14
4	Electronic nematicity in SrRuO_4 . Proceedings of the National Academy of Sciences of the United States of America, 2020, 117, 10654-10659.	8.0	12
5	Strain-Engineered Ferroelastic Structures in PbTiO_3 Films and Their Control by Electric Fields. ACS Applied Materials & Interfaces, 2020, 12, 20691-20703.	0.4	0
6	Harnessing Local Sample Variations to Generate Self-Consistent EELS References for Stoichiometry Quantification. Microscopy and Microanalysis, 2019, 25, 580-581.	9.1	40
7	Exceptionally High, Strongly Temperature Dependent, Spin Hall Conductivity of SrRuO_3 . Nano Letters, 2019, 19, 3663-3670.	5.1	61
8	Synthesis science of SrRuO_3 and CaRuO_3 epitaxial films with high residual resistivity ratios. APL Materials, 2018, 6, .	5.1	33
9	Demystifying the growth of superconducting Sr_2RuO_4 thin films. APL Materials, 2018, 6, .	5.1	16
10	Epitaxial integration and properties of SrRuO_3 on silicon. APL Materials, 2018, 6, .	5.1	2
11	Revealing the hidden heavy Fermi liquid in CaRuO_3 . Physical Review B, 2018, 98, .	5.8	2
12	Sub-Nanosecond Tuning of Microwave Resonators Fabricated on Ruddlesden-Popper Dielectric Thin Films. Advanced Materials Technologies, 2018, 3, 1800090.	2.4	17
13	Rutile IrO_2 superlattices: A hyperconnected analog to the Ruddlesden-Popper structure. Physical Review Materials, 2018, 2, .	2.2	13
14	Characterization of ErAs:GaAs and LuAs:GaAs Superlattice Structures for Continuous-Wave Terahertz Wave Generation through Plasmonic Photomixing. Journal of Infrared, Millimeter, and Terahertz Waves, 2016, 37, 640-648.		0
15	3.4 μm diode lasers employing Al-free GaInAsSb/GaSb MQW active regions at 20 μm . , 2013, , .		13
16	Structural and optical studies of nitrogen incorporation into GaSb-based GaInSb quantum wells. Applied Physics Letters, 2012, 100, 021103.	3.3	1
17	Charge-compensated high gain InAs avalanche photodiodes. , 2012, , .		13
18	Suppression of planar defects in the molecular beam epitaxy of GaAs/ErAs/GaAs heterostructures. Applied Physics Letters, 2011, 99, 072120.	3.3	13

#	ARTICLE	IF	CITATIONS
19	Surface segregation effects of erbium in GaAs growth and their implications for optical devices containing ErAs nanostructures. Applied Physics Letters, 2011, 98, 121108.	3.3	11
20	Enhanced conductivity of tunnel junctions employing semimetallic nanoparticles through variation in growth temperature and deposition. Applied Physics Letters, 2010, 96, .	3.3	33
21	Compact Models of Spreading Resistances for Electrical/Thermal Design of Devices and ICs. IEEE Transactions on Electron Devices, 2007, 54, 1734-1743.	3.0	29